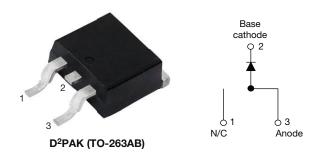
Vishay Semiconductors

High Performance Schottky Rectifier, 8 A



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PRIMARY CHARACTERISTICS						
I _{F(AV)} 8 A						
V _R	80 V, 100 V					
V _F at I _F	0.58 V					
I _{RM}	7 mA at 125 °C					
T _J max.	175 °C					
E _{AS}	7.5 mJ					
Package	D ² PAK (TO-263AB)					
Circuit configuration	Single					

FEATURES

- 175 °C T_J operation
- · Low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- · Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Designed and qualified according to JEDEC[®]-JESD 47
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

The VS-8TQ... Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	CHARACTERISTICS VALUES					
I _{F(AV)}	Rectangular waveform	8	A				
V _{RRM}	Range	80/100	V				
I _{FSM}	t _p = 5 μs sine	850	А				
V _F	8 A _{pk} , T _J = 125 °C	0.58	V				
TJ	Range	-55 to +175	۵°				

VOLTAGE RATINGS									
PARAMETER	SYMBOL	VS-8TQ080S-M3	VS-8TQ100S-M3	UNITS					
Maximum DC reverse voltage	V _R	80	100	V					
Maximum working peak reverse voltage	V _{RWM}	80	100	v					

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST COND	TEST CONDITIONS					
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T_C = 157 °C	8	А				
Maximum peak one cycle		5 µs sine or 3 µs rect. pulse	Following any rated load	850				
non-repetitive surge current See fig. 7	I _{FSM}	10 ms sine or 6 ms rect. pulse	condition and with rated V _{RRM} applied	230	A			
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 0.50 A, L = 60 mH		7.50	mJ			
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		0.50	А			

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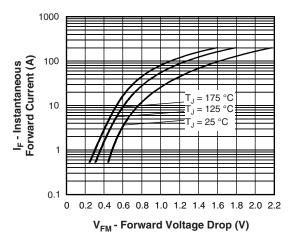
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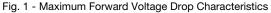
ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS					
Maximum forward voltage drop See fig. 1		8 A	T ₁ = 25 °C	0.72				
	V _{FM} ⁽¹⁾	16 A	1j=25 C	0.88	v			
		8 A	T,₁ = 125 °C	0.58				
		16 A	1j = 125 0	0.69				
Maximum reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	0.55	m (
See fig. 2	'RM \''	T _J = 125 °C	VR - naleu VR	7	mA			
Maximum junction capacitance	CT	$V_{R} = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		500	pF			
Typical series inductance	Ls	Measured lead to lead 5 r	8	nH				
Maximum voltage rate of change	dV/dt	Rated V _R	10 000	V/µs				

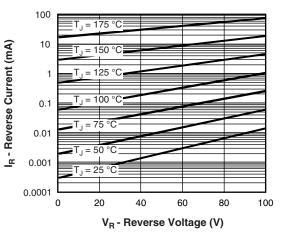
Note

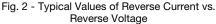
 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

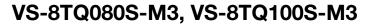
THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and storage temperature range		T _J , T _{Stg}		-55 to +175	°C			
Maximum thermal resistance, junction to case		R _{thJC}	DC operation See fig. 4	2.0	°C/W			
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth, and greased	0.50	0/10			
Approvimete weight				2	g			
Approximate weight				0.07	OZ.			
Mounting torque	minimum			6 (5)	kgf · cm			
Mounting torque	maximum			12 (10)	(lbf · in)			
Marking device			Case style $D^2 DAK (TO 262AB)$	8TQ0)80S			
			Case style D ² PAK (TO-263AB)	8TQ1	00S			











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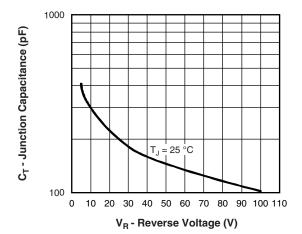


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

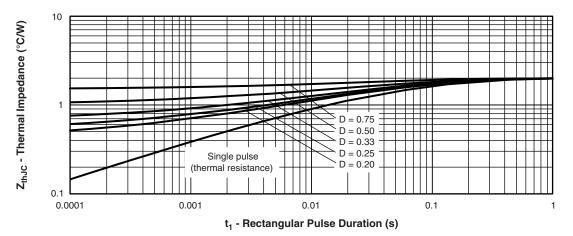
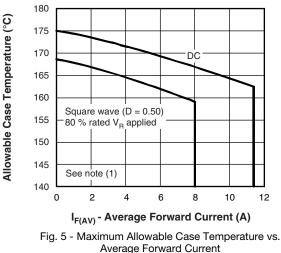
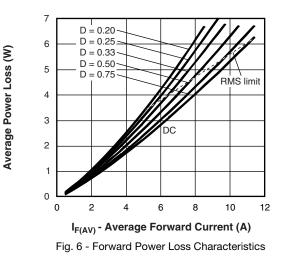


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics



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VS-8TQ080S-M3, VS-8TQ100S-M3

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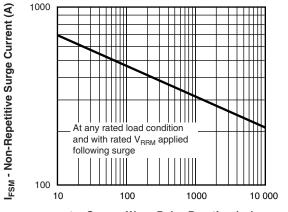




Fig. 7 - Maximum Non-Repetitive Surge Current

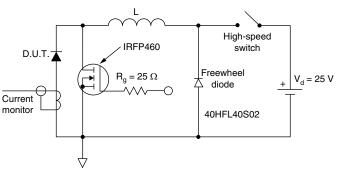
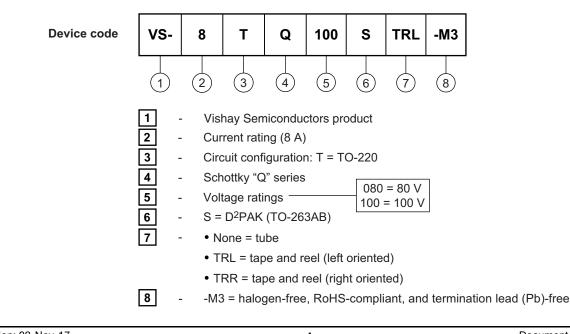


Fig. 8 - Unclamped Inductive Test Circuit

Note

ORDERING INFORMATION TABLE



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VS-8TQ080S-M3, VS-8TQ100S-M3

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ORDERING INFORMATION									
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-8TQ080S-M3	50	1000	Antistatic plastic tubes						
VS-8TQ080STRR-M3	800	800	13" diameter reel						
VS-8TQ080STRL-M3	800	800	13" diameter reel						
VS-8TQ100S-M3	50	1000	Antistatic plastic tubes						
VS-8TQ100STRR-M3	800	800	13" diameter reel						
VS-8TQ100STRL-M3	800	800	13" diameter reel						

LINKS TO RELATED DOCUMENTS						
Dimensions www.vishay.com/doc?96164						
Part marking information	www.vishay.com/doc?95444					
Packaging information	www.vishay.com/doc?96424					
SPICE model	www.vishay.com/doc?96227					

Outline Dimensions



D²PAK

DIMENSIONS in millimeters and inches

www.vishay.com

SHA



SYMBOL	MILLIMETERS		INC	INCHES		NOTES	SYMBOL	MILLIM	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STWDUL	MIN.	MAX.	MIN.	MAX.	NOTES
A	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			E	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5 M-1994

⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

⁽⁵⁾ Datum A and B to be determined at datum plane H

⁽⁶⁾ Controlling dimension: inch

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-263AB

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